# technical memorandum

# Daresbury Laboratory

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AN "ELECTRONICALLY COOLED" PRE-AMPLIFIER

by

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## IMPORTANT

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#### 1. INTRODUCTION

Most detectors used in nuclear physics experiments provide electrical outputs which may be charge, current or voltage. To process such signals sensitive wideband pre-amplifiers are used. The requirement for large bandwidth results in an increased noise, as typically the pre-amplifier output noise is directly proportional to bandwidth. It is essential that a pre-amplifier should intorduce as little noise as possible, thus it should have the minimum equivalent input noise.

The report describes a low noise wideband pre-amplifier suitable for processing low level output signals from delay lines.

#### 2. PRINCIPLE OF OPERATION

The pre-amplifier was developed for use with delay line readout from MWPC's. For optimum performance the pre-amplifier should provide an impedance match to the line. In order for the output to be independent of the characteristic impedance of a line, a charge sensitive configuration was chosen. The simple solution shown in fig. 1 where a low input impedance charge sensitive pre-amplifier with a matching resistor R<sub>O</sub> is used to terminate a line, suffers from a major disadvantage, namely the unwanted Johnson noise generated in R<sub>O</sub>. This noise has a spectral density

$$v = \sqrt{4kTR_0} \qquad v. \ Hz^{-\frac{1}{2}} \tag{1}$$

where

k = Boltzman's constant

T = temperature of the resistor

A pre-amplifier with a resistive imput impedance and an equivalent input noise voltage independent of that resistance has been described (1). It uses a gain element with a transconductance  $-g_m$  and an infinite input impedance as shown in fig. 2. It can be seen that

$$i_F = i_i \tag{2}$$

and the output current is given by

$$i_{O} = -g_{m} V_{i}$$
 (3)

The output voltage is

$$V_{O} = V_{i} - i_{F} \frac{1}{sC_{F}}$$
 (4)

The current in the load capacitor is

$$i_{T} = i_{P} + i_{O} = i_{A} - gm V_{A}$$
 (5)

which gives rise to an output voltage

$$\mathbf{v}_{o} = \mathbf{i}_{\mathbf{L}} \frac{1}{\mathbf{s} \mathbf{C}_{o}} = (\mathbf{i}_{\mathbf{1}} - \mathbf{g}_{\mathbf{m}} \mathbf{v}_{\mathbf{1}}) \frac{1}{\mathbf{s} \mathbf{C}_{o}}$$
 (6)

From eqns (4) and (6)

$$(i_1 - g_m v_1) \frac{1}{sC_0} = v_1 - i_F \frac{1}{sC_0}$$
 (7)

from which the input impedance can be found

$$z_i = \frac{v_i}{t_i} = \frac{1/sC_O + 1/sC_F}{1 + g_m/sC_O}$$
 (8)

which for gm/sCo >> 1 gives

$$z_{i} \doteq \frac{1}{g_{m}} + \frac{c_{o}}{g_{m} c_{F}} = \frac{1}{g_{m}} (1 + \frac{c_{o}}{c_{F}})$$
 (10)

Thus for real values of transconductance  $g_m$  the input impedance will also be real. For a practical circuit  $C_Q >> C_F$  and the input resistance becomes

$$R_{i} \stackrel{\circ}{=} \frac{C_{o}}{g_{m}C_{F}} \tag{11}$$

In a pre-amplifier the equivalent input noise is mainly due to the input active device and its biasing resistors. If a low noise input FET which has an equivalent input noise resistance  $\mathbf{r}_n$  is used in implementing a pre-amplifier with an input resistance, given by eqn (11), greater than  $\mathbf{r}_n$ , then the pre-amplifier input resistance will have a noise temperature  $\mathbf{T}_n < \mathbf{T}$ 

$$T_n = T \frac{r_n}{R_4}$$
 (12)

where T = ambient temperature.

Thus the pre-amplifier will appear to have a cooled input resistance.

#### 3. CIRCUIT DESCRIPTION

If the pre-amplifier is to provide a good match to the delay line it is necessary to stabilize its input resistance. Figure 3 shows a schematic diagram of a charge sensitive pre-amplifier in which the transconductance can be precisely defined by passive components and made independent of the active components. The transconductance is given by:

$$g_{\rm m} = \frac{(1 + R_2/R_1)}{R_3} \tag{13}$$

which, for R<sub>2</sub> >> R<sub>1</sub>, simplifies to:

$$g_{m} = \frac{R_{2}}{R_{1} R_{3}}$$
 (14)

A feedback resistor  $\mathbf{R}_{\overline{\mathbf{r}}}$  is provided to restore the output to its quiescent value with a time constant

$$\tau' = R_F C_F \tag{15}$$

To facilitate the use of the circuit as a timing amplifier, a wideband differentiator and current amplifier are provided. Figure 4 shows a schematic diagram of the differentiator timing circuit.

The output of the charge sensitive pre-amplifier is fed into the timing circuit. The output voltage of which is given by:

$$V_{O}^{\dagger} = -\frac{R_{6} R_{L} (R_{4} + R_{5})}{(R_{6} + R_{L}) R_{5}} C \frac{dV_{O}}{dt}$$
 (16)

which for  $R_L << R_6$  and  $R_5 << R_4$  simplifies to

$$v'_{o} = -\frac{R_{L}}{R_{S}} \frac{R_{4}}{c} \frac{dv_{o}}{dt}$$
 (17)

But the input voltage  $\mathbf{V}_{\mathbf{O}}$  is the integral of the pre-amplifier input current  $\mathbf{i}_i$ 

$$v_o = -\frac{1}{C_F} \int i_i dt \qquad (18)$$

Thus

$$\mathbf{v}_{o}' = \frac{\mathbf{R}_{i_{\downarrow}}}{\mathbf{R}_{5}} \frac{\mathbf{C}}{\mathbf{C}_{\mathbf{F}}} \mathbf{i}_{\mathbf{1}}$$

The complete circuit of the charge sensitive pre-amplifier with timing output is given in fig. 5. Transistors TR1 - TR4 form a high gain amplifier with an open loop gain of approximately  $10^3$  and a stabilized closed loop gain of 23 determined by  $R_7$  and  $R_3$ . Transistor TR5 supplies the current into the variable load capacitor  $C_0$ .

The circuit has an overall transconductance

$$g_{\rm m} = \frac{R_7}{R_7 + R_3} \frac{1}{R_{17}} \stackrel{\cdot}{=} 100 \text{ mA/V}$$
 (19)

and an input resistance

$$R_{1} = 10 \frac{C_{o}}{C_{p}} \Omega$$
 (20)

which can be varied by adjusting Co.

The sensitivity is determined by the feedback capacitor  $C_F$  and is  $1 \frac{V}{pc}$ . Transistors TR7 and TR8 buffer the output of the charge sensitive pre-amplifier and drive the fast differentiator. Transistors TR9 - TR11 form a high gain amplifier with an open loop gain of approximately 250 and a closed loop gain of 38 determined by R25 and R34.

#### 4. PERFORMANCE

The charge sensitive pre-amplifier has a 17 x  $10^6$  gain bandwidth product. When fed by a 1 pF capacitor it gives a minimum output signal risetime of 18 ns. The input resistance can be varied over the range  $50\Omega$  to  $500\Omega$  by adjusting  $C_0$ .

Figure 6 shows the measured equivalent input noise as a function of capacitance connected across the input of the pre-amplifier. The noise was measured using an Ortec 450 spectroscopy amplifier with equal 1 µs differentiating and integrating time constants.

#### ACKNOWLEDGEMENTS

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#### REFERENCES

E. Gatti, P.F. Manfredi, "Low noise current pre-amplifiers for large capacitance semi-conductor detectors and high counting rates",

Proc. 2nd Ispra Nuclear Electronics Symposium.

#### Figure Captions

- Fig. 1 Charge sensitive pre-amplifier terminating a delay line.
- Fig. 2 Schematic diagram of "electronically cooled" charge sensitive pre-amplifier.
- Fig. 3 Schematic diagram of "electronically cooled" charge sensitive pre-amplifier with stabilised input resistance.
- Fig. 4 Schematic diagram of timing circuit.
- Fig. 5 Circuit diagram of "electronically cooled" charge sensitive pre-amplifier and timing amplifier.
- Fig. 6 Equivalent input noise as a function of input capacitance measured using an Ortec 450 amplifier with 1  $\mu s$  equal shaping time constants.

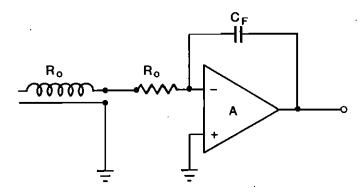
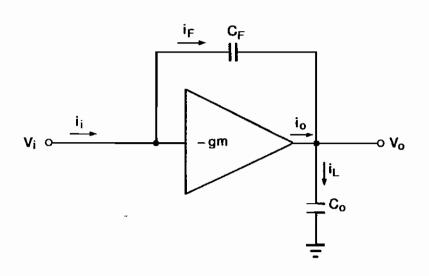


Fig.1



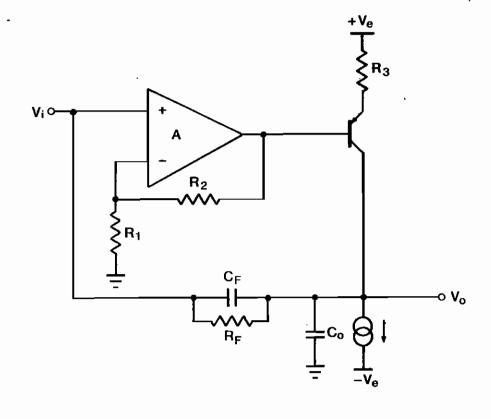


Fig. 2

Fig.3

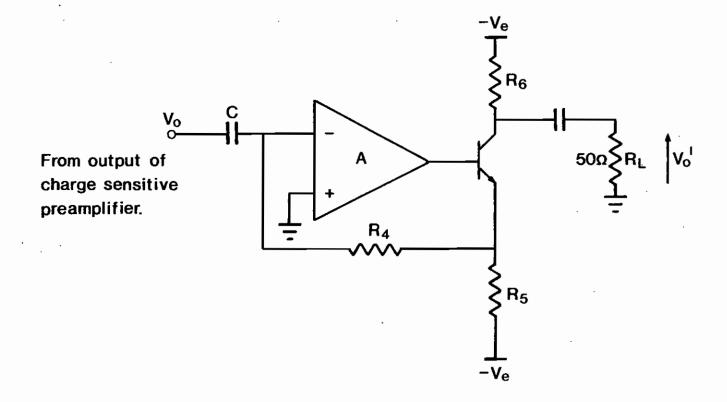


Fig.4

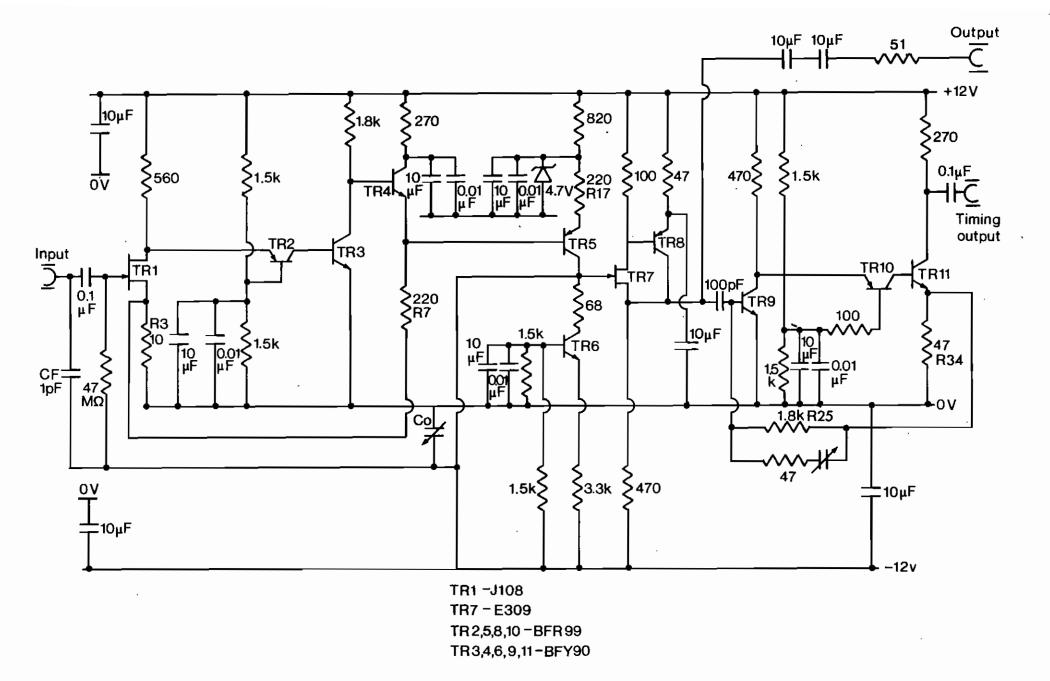


Fig.5

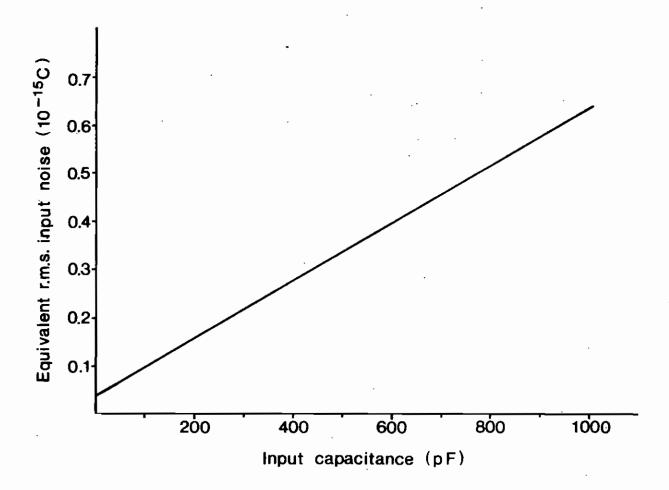


Fig. 6

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